

# 2MBI200VH-170-50

**IGBT Modules** 

# **IGBT MODULE (V series)** 1700V / 200A / 2 in one package

#### Features

High speed switching Voltage drive Low Inductance module structure

#### Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

#### Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T<sub>c</sub>=25°C unless otherwise specified)



Items	Symbols	Conditions	Conditions		Units	
Collector-Emitter voltage	Vces		,	1700	V	
Gate-Emitter voltage	V <sub>GES</sub>				V	
Collector current	Ic	Continuous	Tc=100°C	200		
		Continuous	Tc=25°C	310		
	C pulse	1ms		400	Α	
	-lc			200		
	-I <sub>C pulse</sub>	1ms	,	400		
Collector power dissipation	Pc	1 device		1250	W	
Junction temperature	Ti			175	°C	
Operating junction temperature (under switching conditions)	T <sub>jop</sub>			150		
Case temperature	Tc		,	125		
Storage temperature	T <sub>stg</sub>					
Isolation voltage   between terminal and copper base (*1)	Viso	AC : 1min.	4000		VAC	
Screw torque Mounting (*2)	-			6.0	N m	
Terminals (*3)	-			5.0	IN III	

Note \*1: All terminals should be connected together during the test. Note \*2: Recommendable Value :  $3.0\text{-}6.0~\text{N}\cdot\text{m}$  (M5 or M6) Note \*3: Recommendable Value :  $2.5\text{-}5.0~\text{N}\cdot\text{m}$  (M5)

#### ● Electrical characteristics (at T<sub>i</sub>= 25°C unless otherwise specified)

H	Cymbala	Conditions		Ch	aracterist	tics	Haita
Items	Symbols	Conditions		min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1700V		-	-	2.0	mA
Gate-Emitter leakage current	Iges	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	400	nA
Gate-Emitter threshold voltage	V <sub>GE (th)</sub>	V <sub>CE</sub> = 20V, I <sub>C</sub> = 200mA		6.0	6.5	7.0	V
Collector-Emitter saturation voltage	V	V <sub>GE</sub> = 15V Ic = 200A	T <sub>j</sub> =25°C	-	2.15	2.60	V
	V <sub>CE</sub> (sat)		T <sub>j</sub> =125°C	-	2.55	-	
	(terminal)		T <sub>j</sub> =150°C	-	2.60	-	
	V		T <sub>j</sub> =25°C	-	2.00	2.25	
	V <sub>CE</sub> (sat)		T <sub>j</sub> =125°C	-	2.40	-	
	(chip)		T <sub>j</sub> =150°C	-	2.45	-	
Internal gate resistance	R <sub>G</sub> (int)	-		-	3.8	-	Ω
Input capacitance	Cies	Vce = 10V, Vge = 0V, f = 1MHz		-	19	-	nF
Turn-on time	ton	$V_{\text{CC}}$ = 900V, $I_{\text{C}}$ = 200A $V_{\text{GE}}$ = ±15V, Rg_on= 6.8Ω, Rg_off= 3.6Ω $T_{\text{J}}$ =150°C, $L_{\text{S}}$ = 30nH		-	1150	-	nsec
	tr			-	580	-	
	t <sub>r (i)</sub>			-	60	-	
Turn-off time	toff			-	1050	-	
	tr			-	140	-	
Forward on voltage	V	V <sub>GE</sub> = 0V I <sub>F</sub> = 200A	T <sub>j</sub> =25°C	-	1.95	2.40	V
	(terminal)		T <sub>j</sub> =125°C	-	2.20	-	
	(terminal)		T <sub>j</sub> =150°C	-	2.20	-	
	VF		T <sub>j</sub> =25°C	-	1.80	2.25	
	1		T <sub>j</sub> =125°C	-	2.05	-	
	(chip)		T <sub>j</sub> =150°C	-	2.05	-	
Reverse recovery time	trr	I <sub>F</sub> = 200A	*	-	220	-	nsec

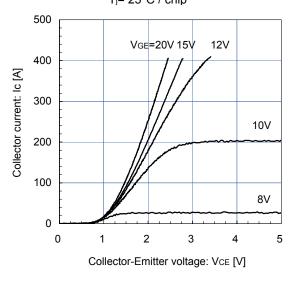
#### Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units	
Items		Conditions	min.	typ.	max.	Ullits	
Thermal resistance(1device)	R <sub>th(j-c)</sub>	IGBT	-	-	0.120	°C/W	
		FWD	-	-	0.160		
Contact thermal resistance (1device) (*4)	R <sub>th(c-f)</sub>	with Thermal Compound	-	0.0125	-		

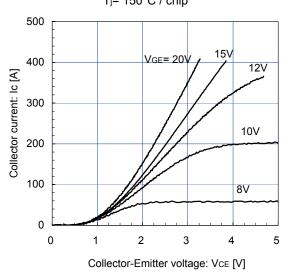
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

#### **■** Characteristics (Representative)

Collector current vs. Collector-Emitter voltage (typ.)  $T_{j}$ = 25°C / chip

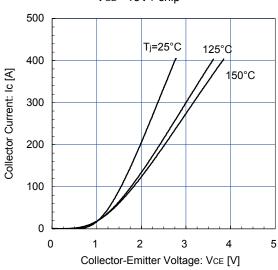


Collector current vs. Collector-Emitter voltage (typ.) T<sub>j</sub>= 150°C / chip

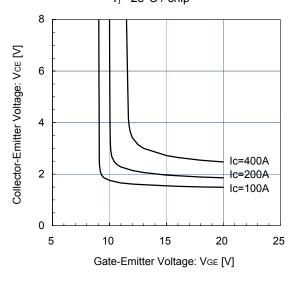


Collector current vs. Collector-Emitter voltage (typ.)

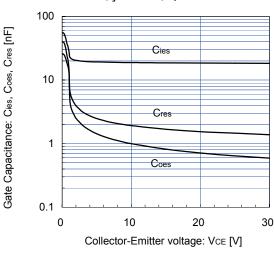
VGE= 15V / chip



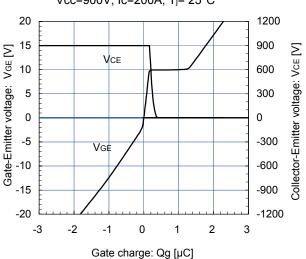
Collector-Emitter voltage vs. Gate-Emitter voltage Tj= 25°C / chip



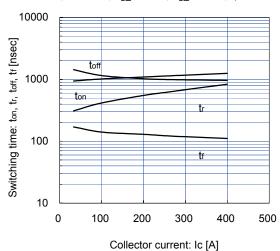
Gate Capacitance vs. Collector-Emitter Voltage VGE= 0V, f= 1MHz, Tj= 25°C



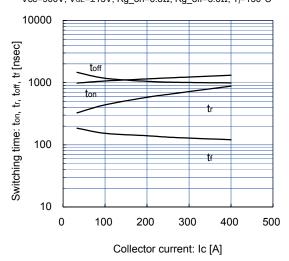
Dynamic Gate Charge (typ.) Vcc=900V, Ic=200A, T<sub>i</sub>= 25°C



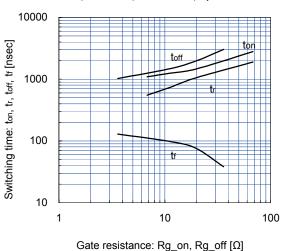
Switching time vs. Collector current (typ.) Vcc=900V,  $VgE=\pm15V$ ,  $Rg_on=6.8\Omega$ ,  $Rg_off=3.6\Omega$ ,  $T_j=125^{\circ}C$ 



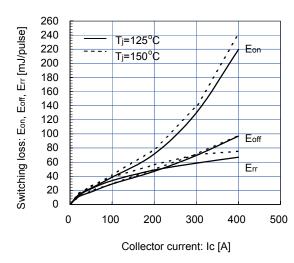
Switching time vs. Collector current (typ.) Vcc=900V, VcE=±15V, Rg\_on=6.8 $\Omega$ , Rg\_off=3.6 $\Omega$ , Tj=150°C



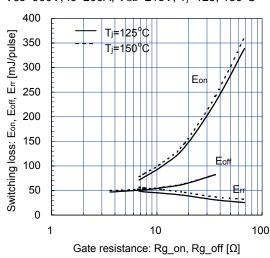
Switching time vs. Gate resistance (typ.) Vcc=900V, Ic=200A, VGE=±15V, Ti=125°C



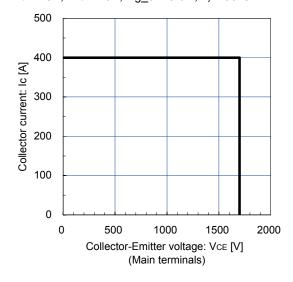
Switching loss vs. Collector current (typ.) Vcc=900V, VgE= $\pm$ 15V, Rg\_on= $6.8\Omega$ , Rg\_off= $3.6\Omega$ 



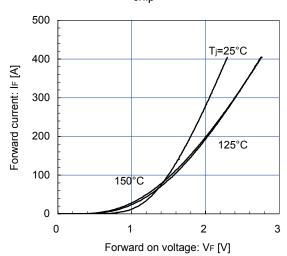
Switching loss vs. Gate resistance (typ.) Vcc=900V, Ic=200A, VgE=±15V, Tj=125, 150°C



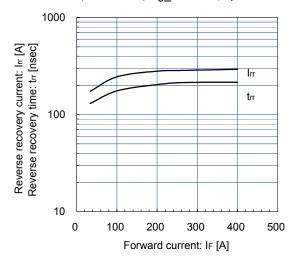
Reverse bias safe operating area (max.) +V<sub>GE</sub>=15V, -V<sub>GE</sub>=15V, Rg\_off=3.6 $\Omega$ , Tj=150°C



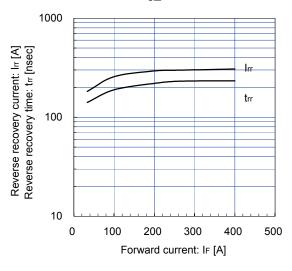
Forward Current vs. Forward Voltage (typ.) chip



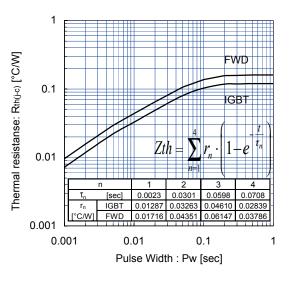
Reverse Recovery Characteristics (typ.) Vcc=900V,  $VgE=\pm15V$ ,  $Rg\_on=6.8\Omega$ ,  $T_j=125^{\circ}C$ 



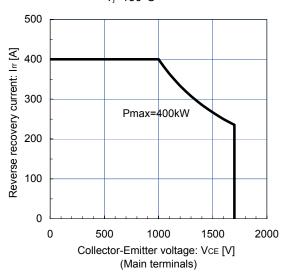
Reverse Recovery Characteristics (typ.) Vcc=900V,  $VgE=\pm15V$ ,  $Rg_on=6.8\Omega$ ,  $Tj=150^{\circ}C$ 



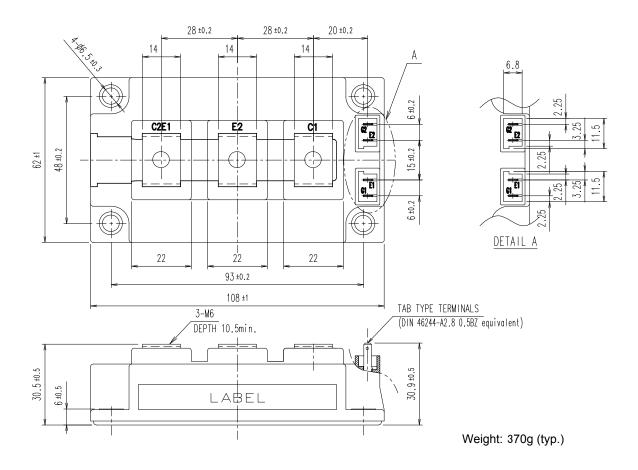
Transient Thermal Resistance (max.)



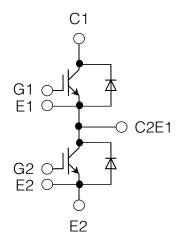
FWD safe operating area (max.)  $T_i=150$  °C



## ■ Outline Drawings, mm



## **■** Equivalent Circuit Schematic



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- Communications equipment (terminal devices)
- Measurement equipment

- Machine tools
- Audiovisual equipment
- Electrical home appliances
   Personal equipment (terminal devices)
- Personal equipment
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   Medical equipment
- Safety devices

- modical equipment
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